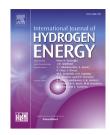
international journal of hydrogen energy XXX (2018) I-8



Available online at www.sciencedirect.com

ScienceDirect



journal homepage: www.elsevier.com/locate/he

Plasmonic Ag nanoparticles decorated NaNbO₃ nanorods for efficient photoelectrochemical water splitting

Dheeraj Kumar, Simrjit Singh, Neeraj Khare*

Department of Physics, Indian Institute of Technology Delhi, Haus Khaz, New Delhi 110016, India

ARTICLE INFO

Article history: Received 8 January 2018 Received in revised form 10 March 2018 Accepted 12 March 2018 Available online xxx

Keywords: NaNbO₃ Nanorods Ag nanoparticles Water splitting

ABSTRACT

In the present work, photoanodes comprising of NaNbO₃ nanorods and Ag nanoparticles decorated NaNbO₃ nanorods have been fabricated by using hydrothermal and chemical solution method respectively. Photoelectrochemical water splitting performance of the fabricated photoanodes have been measured and it is found that Ag decorated NaNbO₃ nanorods exhibit ~4 fold enhancement in photocurrent as compared to bare NaNbO₃ nanorods. The enhancement in the photoelectrochemical water splitting activity of Ag decorated NaNbO₃ nanorods is attributed to efficient charge carrier separation and visible light sensitization due to Ag nanoparticles on NaNbO₃ nanorods.

© 2018 Published by Elsevier Ltd on behalf of Hydrogen Energy Publications LLC.

Introduction

Hydrogen, due to its high-energy density and environment friendly nature is proven to be a potential energy carrier for future [1,2]. Photoelectrochemical (PEC) water splitting is a promising method for the generation of hydrogen (H₂) using the abundant solar energy and water [3]. In the PEC process, the photoelectrode comprising of semiconductor material absorbs photons with energy higher than its band gap resulting in the excitation of electrons from the valence band to the conduction band of the semiconductors. These photogenerated electron-hole pairs drive the reduction and oxidation reactions for the generation of H₂ and O₂, respectively [4–6]. The key requirements for achieving high efficiency in the photoelectrochemical process are the low recombination rate of the electron-hole pairs, chemical stability and efficient absorption of the solar spectra by the semiconductor [7-9]. Several semiconductor oxides such as ZnO [10], TiO₂ [11], WO₃ [12] and Cu₂O [13] have been studied for the generation of hydrogen using photoelectrochemical process.

Recently, complex metal oxides such as BaTiO₃, SrTiO₃ and BiFeO₃ have shown a lot of potential for photoelectrochemical activities due to their excellent stability in aqueous electrolytes [14–17]. Among the complex metal oxides, NaNbO₃ is also shown to possess high photoelectrochemical activity. But the major drawbacks of NaNbO₃ are its wide band gap of (~3.3 eV) and faster recombination rate of the photogenerated charge carriers [18,19]. Due to its wide band gap it absorbs only UV part of the solar spectrum, thereby limiting the use of remaining part [20]. Thus, for an efficient generation of

* Corresponding author.

E-mail address: nkhare@physics.iitd.ernet.in (N. Khare).

https://doi.org/10.1016/j.ijhydene.2018.03.075

0360-3199/© 2018 Published by Elsevier Ltd on behalf of Hydrogen Energy Publications LLC.

Please cite this article in press as: Kumar D, et al., Plasmonic Ag nanoparticles decorated NaNbO₃ nanorods for efficient photoelectrochemical water splitting, International Journal of Hydrogen Energy (2018), https://doi.org/10.1016/j.ijhydene.2018.03.075 hydrogen using NaNbO₃, the two main challenges are (i) to reduce the recombination rate of photogenerated charge carriers and (ii) to shift the photoresponse of NaNbO₃ to the visible light region to utilize maximum part of solar spectra. In the previous reports, the metal nanoparticles coupled with semiconductor have proved to be one of the most effective strategies to improve the photoelectrochemical activity of wide band gap semiconductors in the visible light region, due to their plasmonic effect [21,22]. The metal nanoparticles have been shown to act as photosensitizers, which absorb the visible light irradiation and transfer the charge carriers directly from excited states of metal nanoparticles to the semiconductor [23,24].

NaNbO₃ can be a direct replacement of widely used ZnO and TiO₂ semiconductor thus, to study its visible light responsive PEC activity is of great interest. To the best of our knowledge, there is no report in using Ag decorated NaNbO₃ nanorods for photoelectrochemical applications. In the present work, we have synthesized photoelectrode comprising of Ag nanoparticles decorated NaNbO₃ nanorods for photoelectrochemical application. We have demonstrated that decoration of Ag nanoparticle on NaNbO₃ nanorods shift the optical response of NaNbO₃ nanorods from UV to visible light region result in substantial enhancement in the photoelectrochemical activity. The obtained photocurrent enhancement in Ag decorated NaNbO₃ is much higher compared to previously reported Ag decorated ZnO [25] and TiO₂ [26] semiconductors.

Experimental section

Synthesis of NaNbO3 nanorods

NaNbO₃ nanorods were synthesized by using hydrothermal method. Initially, a 30 mM of niobium pentoxide (Nb₂O₅) was dispersed in 80 ml of deionized water and stirred for half an hour using a magnetic stirrer. Afterwards, a 3 M NaOH solution was added to the above mixture and stirred for further 2 h. Finally, the mixture was transferred to a 100 ml Teflon-lined stainless steel autoclave which was put into an oven at 150 °C for 48 h for the hydrothermal treatment. The resulting white colour paste was washed several times with deionized water and dried at 70 °C for 4 h.

Synthesis of Ag coupled NaNbO3 nanorods

NaNbO₃ nanorods were decorated with silver (Ag) nanoparticles by using a facile chemical solution method. A 100 mg of NaNbO₃ nanorods was dispersed in 50 ml of deionized water and then 25 mM aqueous solution of trisodium citrate was added to the above solution and stirred for 30 min afterwards, 25 mM aqueous solutions of AgNO₃ were added to the above mixture. A 4 ml solution of NaBH₄ was added dropwise into the above mixture and stirred for 1 h. The resulting product was washed 3–4 times with deionized water and finally dried at 70 °C for 2 h. Fig. 1 shows the schematic diagram for the synthesis of NaNbO₃ nanorods and Ag decorated NaNbO₃ nanorods.

Fabrication of photoelectrodes

For the Photoelectrochemical (PEC) measurements, the photoelectrodes were prepared by coating thin films of NaNbO₃ nanorods or Ag decorated NaNbO₃ nanorods onto fluorine doped tin oxide (FTO) substrates by using the spray coating technique. The prepared photoelectrodes were covered with insulating epoxy and only a working area of ~0.9 cm² left open for photoelectrochemical water splitting reactions.

Characterization

X-ray diffraction patterns of nanostructures were taken by using Rigaku Ultima IV diffractometer equipped with Ni filtered Cu Ka radiation ($\lambda = 1.5418$ Å) in the 20 range of 20–60° at a scanning rate of 4°/min. The morphological studies were carried out by using FEI Tecnai (accelerating voltage ~200 kV) transmission electron microscope. The compositional analysis was done by using an energy dispersive X-ray spectroscopy (EDX). Optical spectra were recorded by using Perkin Elmer Lambda 1050 spectrophotometer.

Photoelectrochemical measurements

Photoelectrochemical (PEC) measurements were performed in a conventional three electrode cell assembly, where nanostructured photoelectrode, Platinum wire and Ag/AgCl were used as the working, counter and reference electrodes, respectively. A 0.5 M NaOH solution was used as an electrolyte. The photocurrent density, electrochemical impedance spectroscopy (EIS) and Mott-Schottky measurements were carried out using PEC workstation (Zahner Zennium, PP 211). A halogen lamp with intensity ~100 mW cm⁻² was used as a light source.

Results and discussion

Structural analysis

Fig. 2 shows the XRD patterns of the NaNbO₃ nanorods and Ag decorated NaNbO₃ nanorods. The XRD patterns of NaNbO₃ show the respective peak positions at 20 values of 22.8°, 23.0°, 32.3°, 32.6°, 39.9°, 40.2°, 46.4°, 46.9°, 52.1°, 52.6°, 57.6° and 57.9° corresponding to (101), (020), (200), (121), (031), (022), (202), (040), (301), (141), (321) and (123) diffraction which confirms the formation of the single phase orthorhombic NaNbO₃ (Matched with JCPDS no. 82-0606). For the Ag nanoparticles, peak positions at 20 values of 38.1° and 44.3° corresponding to (111) and (200) diffraction planes confirmed the formation of cubic phase of Ag nanoparticles. The XRD pattern of Ag coupled NaNbO₃ nanocomposite exhibit peaks corresponding to both Ag and NaNbO₃, which indicates the presence of both the materials in the nanostructures.

Morphological studies

The morphological analysis of the NaNbO $_3$ nanorods and Ag decorated NaNbO $_3$ nanorods was carried out using

Download English Version:

https://daneshyari.com/en/article/7706220

Download Persian Version:

https://daneshyari.com/article/7706220

Daneshyari.com